16-bit dual supply translating transceiver; 3-state

Rev. 10 — 9 April 2019

Product data sheet

1. General description

The 74ALVC164245 is a high-performance, low-power, low-voltage, Si-gate CMOS device, superior to most advanced CMOS compatible TTL families.

The 74ALVC164245 is a 16-bit (dual octal) dual supply translating transceiver featuring non-inverting 3-state bus compatible outputs in both send and receive directions. It is designed to interface between a 3 V and 5 V bus in a mixed 3 V and 5 V supply environment.

This device can be used as two 8-bit transceivers or one 16-bit transceiver.

The direction control inputs (1DIR and 2DIR) determine the direction of the data flow. nDIR (active HIGH) enables data from nAn ports to nBn ports. nDIR (active LOW) enables data from nBn ports to nAn ports. The output enable inputs (1 \overline{OE} and 2 \overline{OE}), when HIGH, disable both nAn and nBn ports by placing them in a high-impedance OFF-state. Pins nAn, n \overline{OE} and nDIR are referenced to V_{CC(A)} and pins nBn are referenced to V_{CC(B)}.

In suspend mode, when one of the supply voltages is zero, there will be no current flow from the non-zero supply towards the zero supply. The nAn-outputs must be set 3-state and the voltage on the A-bus must be smaller than V_{diode} (typical 0.7 V). $V_{CC(B)} \ge V_{CC(A)}$ (except in suspend mode).

2. Features and benefits

- 5 V tolerant inputs/outputs for interfacing with 5 V logic
- Wide supply voltage range:
 - 3 V port (V_{CC(A)}): 1.5 V to 3.6 V
 - 5 V port (V_{CC(B)}): 1.5 V to 5.5 V
- CMOS low power consumption
- Direct interface with TTL levels
- Control inputs voltage range from 2.7 V to 5.5 V
- Inputs accept voltages up to 5.5 V
- High-impedance outputs when $V_{CC(A)}$ or $V_{CC(B)} = 0 V$
- Complies with JEDEC standard JESD8-B/JESD36
- ESD protection:
 - HBM JESD22-A114F exceeds 2000 V
 - MM JESD22-A115-A exceeds 200 V
- Specified from -40 °C to +85 °C and -40 °C to +125 °C

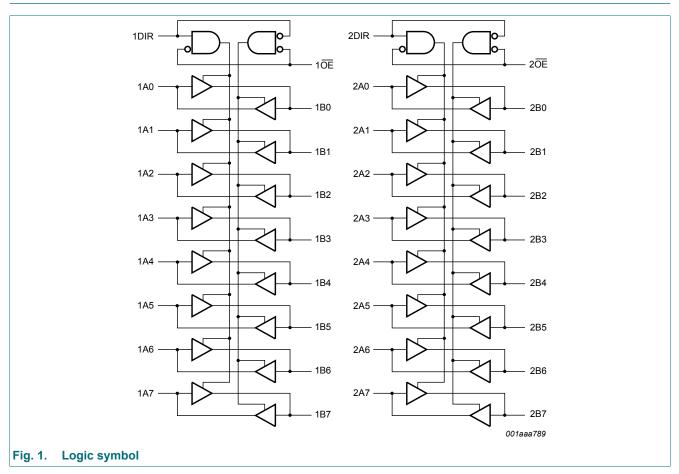
3. Ordering information

Table 1. Ordering information

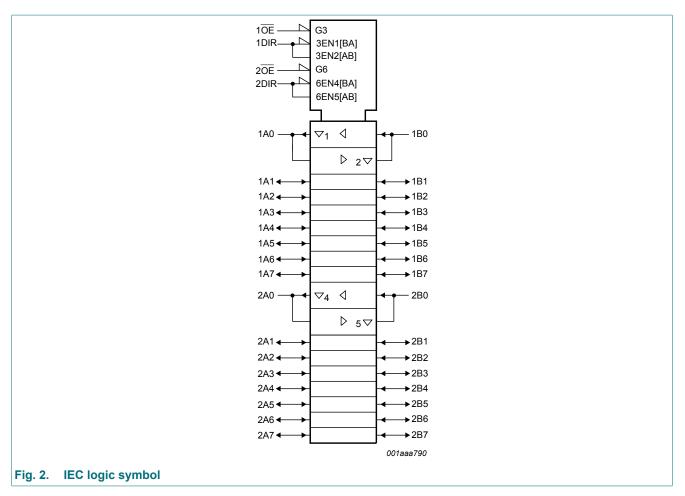
Type number	Package						
	Temperature range	Name	Description	Version			
74ALVC164245DL	-40 °C to +125 °C	SSOP48	plastic shrink small outline package; 48 leads; body width 7.5 mm	SOT370-1			
74ALVC164245DGG	-40 °C to +125 °C	TSSOP48	plastic thin shrink small outline package; 48 leads; body width 6.1 mm	SOT362-1			

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4. Functional diagram



16-bit dual supply translating transceiver; 3-state



5. Pinning information

5.1. Pinning

48 1<u>OE</u> 1DIR 1 1B0 2 47 1A0 1B1 3 46 1A1 GND 4 45 GND 1B2 5 44 1A2 1B3 6 43 1A3 V_{CC(B)} 7 42 V_{CC(A)} 41 1A4 1B4 8 40 1A5 1B5 9 GND 10 39 GND 38 1A6 1B6 11 1B7 12 37 1A7 74ALVC164245 2B0 13 36 2A0 2B1 14 35 2A1 34 GND GND 15 33 2A2 2B2 16 32 2A3 2B3 17 31 V_{CC(A)} V_{CC(B)} 18 2B4 19 30 2A4 2B5 20 29 2A5 GND 21 28 GND 2B6 22 27 2A6 2B7 23 26 2A7 2DIR 24 25 20E 001aab037 Pin configuration SOT370-1 (SSOP48) and SOT362-1 (TSSOP48) Fig. 3.

5.2. Pin description

Table 2. Pin description

Symbol	Pin	Description
1DIR, 2DIR	1, 24	direction control input
1B0, 1B1, 1B2, 1B3, 1B4, 1B5, 1B6, 1B7	2, 3, 5, 6, 8, 9, 11, 12	data input/output
2B0, 2B1, 2B2, 2B3, 2B4, 2B5, 2B6, 2B7	13, 14, 16, 17, 19, 20, 22, 23	data input/output
GND	4, 10, 15, 21, 28, 34, 39, 45	ground (0 V)
V _{CC(B)}	7, 18	supply voltage B (5 V bus)
10E, 20E	48, 25	output enable input (active LOW)
1A0, 1A1, 1A2, 1A3, 1A4, 1A5, 1A6, 1A7	47, 46, 44, 43, 41, 40, 38, 37	data input/output
2A0, 2A1, 2A2, 2A3, 2A4, 2A5, 2A6, 2A7	36, 35, 33, 32, 30, 29, 27, 26	data input/output
V _{CC(A)}	31, 42	supply voltage A (3 V bus)

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6. Functional description

Table 3. Function table

H = HIGH voltage level; L = LOW voltage level; X = don't care; Z = high-impedance OFF-state.

-		Outputs		
nŌE nDIR		nAn	nBn	
L	L	nAn = nBn	inputs	
L	Н	inputs	nBn = nAn	
Н	Х	Z	Z	

7. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions		Min	Max	Unit
V _{CC(B)}	supply voltage B	$V_{CC(B)} \ge V_{CC(A)}$		-0.5	+6.0	V
V _{CC(A)}	supply voltage A	$V_{CC(B)} \ge V_{CC(A)}$		-0.5	+4.6	V
I _{IK}	input clamping current	V ₁ < 0 V		-50	-	mA
VI	input voltage		[1]	-0.5	+6.0	V
V _{I/O}	input/output voltage			-0.5	V _{CC} + 0.5	V
I _{OK}	output clamping current	$V_{\rm O}$ > $V_{\rm CC}$ or $V_{\rm O}$ < 0 V		-	±50	mA
Vo	output voltage	output HIGH or LOW	[1]	-0.5	V _{CC} + 0.5	V
		output 3-state	[1]	-0.5	+6.0	V
I _{O(sink/source)}	output sink or source current	$V_{O} = 0 V \text{ to } V_{CC}$		-	±50	mA
I _{CC}	supply current			-	100	mA
I _{GND}	ground current			-100	-	mA
T _{stg}	storage temperature			-65	+150	°C
Tj	junction temperature		[2]	-	+150	°C
P _{tot}	total power dissipation	T _{amb} = -40 °C to +125 °C	[3]	-	500	mW

[1] The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

[2] The performance capability of a high-performance integrated circuit in conjunction with its thermal environment can create junction temperatures which are detrimental to reliability.

[3] Above 60 °C the value of P_{tot} derates linearly with 5.5 mW/K.

8. Recommended operating conditions

Symbol	Parameter	Conditions	Min	Тур	Мах	Unit
V _{CC(B)}	supply voltage B	$V_{CC(B)} \ge V_{CC(A)}$				
		maximum speed performance	2.7	-	5.5	V
		low-voltage applications	1.5	-	5.5	V
V _{CC(A)}	supply voltage A	$V_{CC(B)} \ge V_{CC(A)}$				
		maximum speed performance	2.7	-	3.6	V
		low-voltage applications	1.5	-	3.6	V
VI	input voltage	control inputs: nOE and nDIR	0	-	5.5	V
V _{I/O}	input/output voltage	nAn port	0	-	V _{CC(A)}	V
		nBn port	0	-	V _{CC(B)}	V
Vo	output voltage	nAn port	0	-	V _{CC(A)}	V
		nBn port	0	-	V _{CC(B)}	V
T _{amb}	ambient temperature		-40	-	+125	°C
Δt/ΔV	input transition rise and fall rate	V _{CC(A)} = 2.7 V to 3.0 V	0	-	20	ns/V
		V _{CC(A)} = 3.0 V to 3.6 V	0	-	10	ns/V
		V _{CC(B)} = 3.0 V to 4.5 V	0	-	20	ns/V
		V _{CC(B)} = 4.5 V to 5.5 V	0	-	10	ns/V

Table 5 Recor ended operating conditions

9. Static characteristics

Table 6. Static characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions		-40 °	°C to +85 °	С	-40 °C to	+125 °C	Unit
				Min	Typ [1]	Мах	Min	Max	
V _{IH}	HIGH-level	nBn port							
	input voltage	V _{CC(B)} = 3.0 V to 5.5 V	[2]	2.0	-	-	2.0	-	V
		nAn port, nOE and nDIR							
	V _{CC(A)} = 3.0 V to 3.6 V		2.0	-	-	2.0	-	V	
		V _{CC(A)} = 2.3 V to 2.7 V	[2]	1.7	-	-	1.7	-	V
V _{IL}	LOW-level	nBn port							
	input voltage	V _{CC(B)} = 4.5 V to 5.5 V	[2]	-	-	0.8	-	0.8	V
		V _{CC(B)} = 3.0 V to 3.6 V	[2]	-	-	0.7	-	0.7	V
		nAn port, nOE and nDIR							
		V _{CC(A)} = 3.0 V to 3.6 V		-	-	0.8	-	0.8	V
		V _{CC(A)} = 2.3 V to 2.7 V	[2]	-	-	0.7	-	0.7	V

Symbol	Parameter	Conditions	-40 °C	c to +85 °	С	-40 °C to +	-125 °C	Unit
			Min	Typ [1]	Мах	Min	Max	1
V _{OH}	HIGH-level	nBn port; V _I = V _{IH} or V _{IL}						
	output voltage	I _O = -24 mA; V _{CC(B)} = 4.5 V	V _{CC(B)} - 0.8	-	-	V _{CC(B)} - 1.2	-	V
		I _O = -12 mA; V _{CC(B)} = 4.5 V	V _{CC(B)} - 0.5	-	-	V _{CC(B)} - 0.8	-	V
		I _O = -18 mA; V _{CC(B)} = 3.0 V	V _{CC(B)} - 0.8	-	-	V _{CC(B)} - 1.0	-	V
		I _O = -100 μA; V _{CC(B)} = 3.0 V	V _{CC(B)} - 0.2	V _{CC(B)}	-	V _{CC(B)} - 0.3	-	V
		nAn port; V _I = V _{IH} or V _{IL}						
		I _O = -24 mA; V _{CC(A)} = 3.0 V	V _{CC(A)} - 0.7	-	-	V _{CC(A)} - 1.0	-	V
		I _O = -100 μA; V _{CC(A)} = 3.0 V	V _{CC(A)} - 0.2	-	-	V _{CC(A)} - 0.3	-	V
		I _O = -12 mA; V _{CC(A)} = 2.7 V	V _{CC(A)} - 0.5	-	-	V _{CC(A)} - 0.8	-	V
		I _O = -8 mA; V _{CC(A)} = 2.3 V	V _{CC(A)} - 0.6	-	-	V _{CC(A)} - 0.6	-	V
		I _O = -100 μA; V _{CC(A)} = 2.3 V	V _{CC(A)} - 0.2	V _{CC(A)}	-	V _{CC(A)} - 0.3	-	V
V _{OL}	LOW-level	nBn port; V _I = V _{IH} or V _{IL}						
	output voltage	I _O = 24 mA; V _{CC(B)} = 4.5 V	-	-	0.55	-	0.80	V
		I _O = 12 mA; V _{CC(B)} = 4.5 V	-	-	0.40	-	0.60	V
		I _O = 100 μA; V _{CC(B)} = 4.5 V	-	-	0.20	-	0.30	V
		I _O = 18 mA; V _{CC(B)} = 3.0 V	-	-	0.55	-	0.80	V
		I _O = 100 μA; V _{CC(B)} = 3.0 V	-	-	0.20	-	0.30	V
		nAn port; V _I = V _{IH} or V _{IL}						
		I _O = 24 mA; V _{CC(A)} = 3.0 V	-	-	0.55	-	0.80	V
		I _O = 100 μA; V _{CC(A)} = 3.0 V	-	-	0.20	-	0.30	V
		I _O = 12 mA; V _{CC(A)} = 2.7 V	-	-	0.40	-	0.60	V
		I _O = 12 mA; V _{CC(A)} = 2.3 V	-	-	0.60	-	0.60	V
		I _O = 100 μA; V _{CC(A)} = 2.3 V	-	-	0.20	-	0.20	V
l _l	input leakage current	V _l = 5.5 V or GND	-	±0.1	±5	-	±10	μA
I _{OZ}	OFF-state output current	$V_{I} = V_{IH} \text{ or } V_{IL};$ [3] $V_{O} = V_{CC} \text{ or } GND$	-	±0.1	±10	-	±20	μA
I _{CC}	supply current	$V_{I} = V_{CC}$ or GND; $I_{O} = 0$ A	-	0.1	40	-	80	μA
ΔI _{CC}	additional supply current	per control pin; $V_I = V_{CC} - 0.6 V$; [4] $I_O = 0 A$	-	5	500	-	5000	μA
CI	input capacitance		-	4.0	-	-	-	pF
C _{I/O}	input/output capacitance	nAn and nBn port	-	5.0	-	-	-	pF

[4] $V_{CC(A)} = 2.7 \text{ V}$ to 3.6 V: other inputs at $V_{CC(A)}$ or GND; $V_{CC(B)} = 4.5 \text{ V}$ to 5.5 V: other inputs at $V_{CC(B)}$ or GND.

10. Dynamic characteristics

Table 7. Dynamic characteristics

GND = 0 V; $t_r = t_f \le 2.5 ns$; $C_L = 50 pF$; for test circuit see Fig. 6.

Symbol	Parameter	Parameter Conditions		-40 °C to +8	5 °C	-40 °C t	Unit	
				ո Typ <mark>[1]</mark>	Max	Min	Max	1
t _{pd}	propagation	nAn to nBn; see Fig. 4	[2]					
	delay	V _{CC(A)} = 2.3 V to 2.7 V; V _{CC(B)} = 3.0 V to 3.6 V	1.5	3.3	7.6	1.5	9.5	ns
		V _{CC(A)} = 2.7 V; V _{CC(B)} = 4.5 V to 5.5 V	1.0	3.0	5.9	1.0	7.5	ns
	V _{CC(A)} = 3.0 V to 3.6 V; V _{CC(B)} = 4.5 V to 5.5 V	1.0	2.9	5.8	1.0	7.5	ns	
		nBn to nAn; see Fig. 4	[2]					
		V _{CC(A)} = 2.3 V to 2.7 V; V _{CC(B)} = 3.0 V to 3.6 V	1.0	3.0	7.6	1.0	9.5	ns
		V _{CC(A)} = 2.7 V; V _{CC(B)} = 4.5 V to 5.5 V	1.0	4.3	6.7	1.0	8.5	ns
		V _{CC(A)} = 3.0 V to 3.6 V; V _{CC(B)} = 4.5 V to 5.5 V	1.2	2.5	5.8	1.2	7.5	ns
t _{en}	enable time	nOE to nBn; see Fig. 5	[3]					
	V _{CC(A)} = 2.3 V to 2.7 V; V _{CC(B)} = 3.0 V to 3.6 V		4.1	11.5	1.5	14.5	ns	
		V _{CC(A)} = 2.7 V; V _{CC(B)} = 4.5 V to 5.5 V	1.5	3.6	9.2	1.5	11.5	ns
		V _{CC(A)} = 3.0 V to 3.6 V; V _{CC(B)} = 4.5 V to 5.5 V	1.0	3.2	8.9	1.0	12.0	ns
		nOE to nAn; see <u>Fig. 5</u>	[3]					
		V _{CC(A)} = 2.3 V to 2.7 V; V _{CC(B)} = 3.0 V to 3.6 V	1.5	4.6	12.3	1.5	15.5	ns
		V _{CC(A)} = 2.7 V; V _{CC(B)} = 4.5 V to 5.5 V	1.5	4.3	9.3	1.5	12.0	ns
		V _{CC(A)} = 3.0 V to 3.6 V; V _{CC(B)} = 4.5 V to 5.5 V	1.0	3.2	8.9	1.0	11.5	ns
t _{dis}	disable time	nOE to nBn; see <u>Fig. 5</u>	[4]					
		V _{CC(A)} = 2.3 V to 2.7 V; V _{CC(B)} = 3.0 V to 3.6 V	2.0	2.7	10.5	2.0	13.5	ns
		V _{CC(A)} = 2.7 V; V _{CC(B)} = 4.5 V to 5.5 V	2.5	4.6	9.0	2.5	11.5	ns
		V _{CC(A)} = 3.0 V to 3.6 V; V _{CC(B)} = 4.5 V to 5.5 V	2.1	4.9	8.6	2.1	11.0	ns
		nOE to nAn; see <u>Fig. 5</u>	[4]					-
		V _{CC(A)} = 2.3 V to 2.7 V; V _{CC(B)} = 3.0 V to 3.6 V	1.0	2.7	9.3	1.0	12.0	ns
		V _{CC(A)} = 2.7 V; V _{CC(B)} = 4.5 V to 5.5 V	1.5	3.5	9.0	1.5	11.5	ns
		V _{CC(A)} = 3.0 V to 3.6 V; V _{CC(B)} = 4.5 V to 5.5 V	2.0	3.2	8.6	2.0	11.0	ns

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Symbol	Parameter	Conditions		-40 °C to +85 °C			-40 °C to	• +125 ℃	Unit
				Min	Тур [1]	Мах	Min	Мах	
C _{PD}	power dissipation capacitance	5 V port: nAn to nBn; V _I = GND to V _{CC} ; V _{CC(B)} = 5 V; V _{CC(A)} = 3.3 V	[5]						
		outputs enabled		-	30	-	-	-	pF
		outputs disabled		-	15	-	-	-	pF
		3 V port: nBn to nAn; V _I = GND to V _{CC} ; V _{CC(B)} = 5 V; V _{CC(A)} = 3.3 V	[5]						
		outputs enabled		-	40	-	-	-	pF
		outputs disabled		-	5	-	-	-	pF

All typical values are measured at nominal voltage for $V_{CC(B)}$ and $V_{CC(A)}$ and at T_{amb} = 25 °C. [1]

 t_{pd} is the same as t_{PLH} and t_{PHL} . [2]

[3] t_{en} is the same as t_{PZL} and t_{PZH} .

[4]

 $t_{dis} \text{ is the same as } t_{PLZ} \text{ and } t_{PHZ}.$ $C_{PD} \text{ is used to determine the dynamic power dissipation (P_D in \mu W). } P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \Sigma (C_L \times V_{CC}^2 \times f_o) \text{ where:}$ [5]

 f_i = input frequency in MHz;

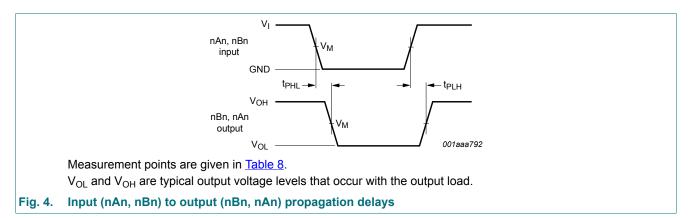
fo = output frequency in MHz;

 C_L = output load capacitance in pF;

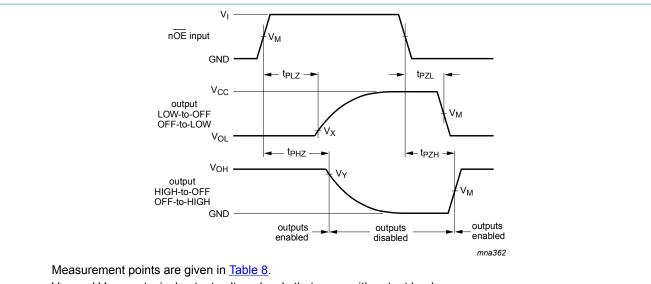
V_{CC} = supply voltage in V;

N = number of inputs switching; $\Sigma(C_L \times V_{CC}^2 \times f_0)$ = sum of outputs.

10.1. Waveforms and test circuit



16-bit dual supply translating transceiver; 3-state

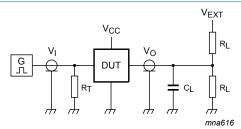


V_{OL} and V_{OH} are typical output voltage levels that occur with output load.

Fig. 5. 3-state enable and disable times

Table 8. Measurement points

Direction	Supply voltage		Input		Output			
	V _{CC(A)}	V _{CC(B)}	VI	V _M	V _M	V _X	V _Y	
nAn port to nBn port	2.3 V to 2.7 V	2.7 V to 3.6 V	V _{CC(A)}	$0.5 \times V_{CC(A)}$	1.5 V	V _{OL(B)} + 0.3 V	V _{OH(B)} - 0.3 V	
nBn port to nAn port	2.3 V to 2.7 V	2.7 V to 3.6 V	2.7 V	1.5 V	$0.5 \times V_{CC(A)}$	V _{OL(A)} + 0.15 V	V _{OH(A)} - 0.15 V	
nAn port to nBn port	2.7 V to 3.6 V	4.5 V to 5.5 V	2.7 V	1.5 V	$0.5 \times V_{CC(B)}$	$0.2 \times V_{CC(B)}$	$0.8 \times V_{CC(B)}$	
nBn port to nAn port	2.7 V to 3.6 V	4.5 V to 5.5 V	3.0 V	1.5 V	1.5 V	V _{OL(A)} + 0.3 V	V _{OH(A)} - 0.3 V	



Test data is given in Table 9.

Definitions for test circuit:

 R_T = Termination resistance should be equal to output impedance Z_0 of the pulse generator.

 C_L = Load capacitance including jig and probe capacitance.

R_L = Load resistance.

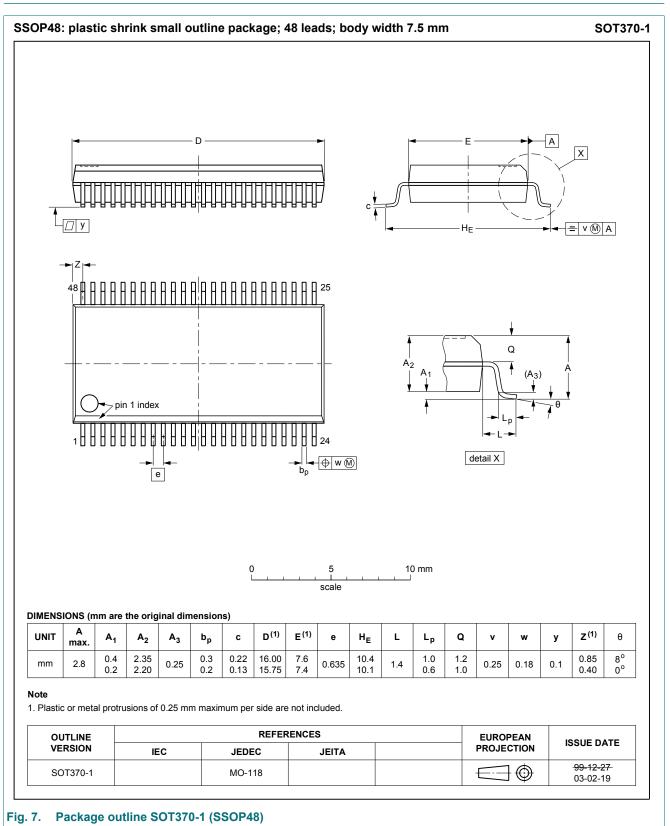
V_{EXT} = External voltage for measuring switching times.

Fig. 6. Test circuit for measuring switching times

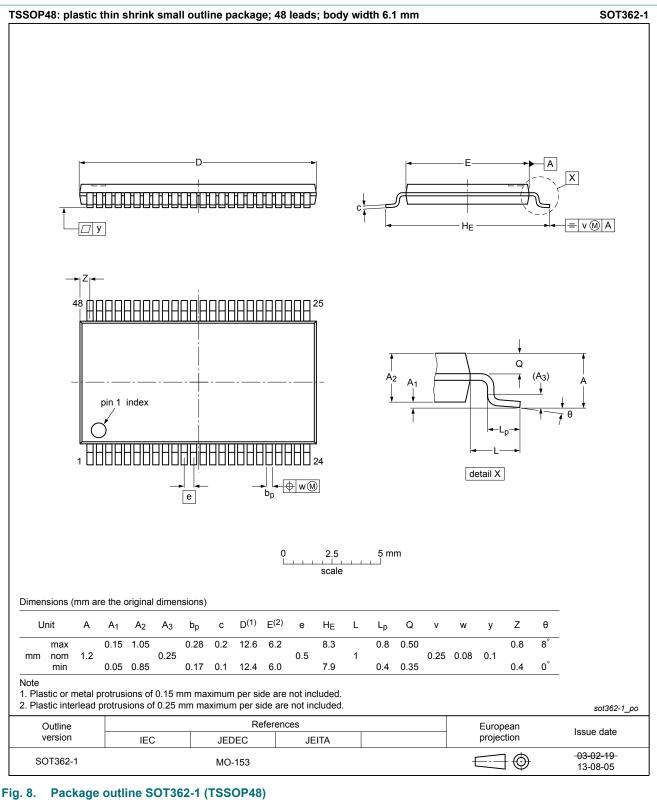
Tabl	e 9	. Tes	t data

Direction	Supply voltage		Load	Load		V _{EXT}		
	V _{CC(A)}	V _{CC(B)}	CL	RL	t _{PLH} , t _{PHL}	t _{PZH} , t _{PHZ}	t _{PZL} , t _{PLZ}	
nAn port to nBn port	2.3 V to 2.7 V	2.7 V to 3.6 V	50 pF	500 Ω	open	GND	$2 \times V_{CC}$	
nBn port to nAn port	2.3 V to 2.7 V	2.7 V to 3.6 V	50 pF	500 Ω	open	GND	6.0 V	
nAn port to nBn port	2.7 V to 3.6 V	4.5 V to 5.5 V	50 pF	500 Ω	open	GND	$2 \times V_{CC}$	
nBn port to nAn port	2.7 V to 3.6 V	4.5 V to 5.5 V	50 pF	500 Ω	open	GND	6.0 V	

11. Package outline



16-bit dual supply translating transceiver; 3-state





12. Abbreviations

Table 10. Abbreviations				
Acronym	Description			
CMOS	Complementary Metal-Oxide Semiconductor			
DUT	Device Under Test			
ESD	ElectroStatic Discharge			
HBM	Human Body Model			
MM	Machine Model			
TTL	Transistor-Transistor Logic			

13. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes		
74ALVC164245 v.10	20190409	Product data sheet	-	74ALVC164245 v.9		
Modifications:	• <u>Table 6</u> : Typo corrected for $V_{OL(max)}$ at $V_{CC(B)}$ = 4.5 V.					
74ALVC164245 v.9	20181112	Product data sheet	-	74ALVC164245 v.8		
Modifications:	of Nexperia Legal texts Type numb	 Inclosing to this data sheet has been redesigned to comply with the identity guidelines of Nexperia. Legal texts have been adapted to the new company name where appropriate. Type number 74ALVC164245BX (SOT1134-2) removed. 				
74ALVC164245 v.8	20120315	Product data sheet	-	74ALVC164245 v.7		
Modifications:	• For type number 74ALVC164245BX the sot code has changed to SOT1134-2.					
74ALVC164245 v.7	20111117	Product data sheet	-	74ALVC164245 v.6		
Modifications:	Legal pages updated.					
74ALVC164245 v.6	20110616	Product data sheet	-	74ALVC164245 v.5		
74ALVC164245 v.5	20100413	Product data sheet	-	74ALVC164245 v.4		
74ALVC164245 v.4	20081111	Product data sheet	-	74ALVC164245 v.3		
74ALVC164245 v.3	20040914	Product data sheet	-	74ALVC164245 v.2		
74ALVC164245 v.2	20040601	Product data sheet	-	74ALVC164245 v.1		
74ALVC164245 v.1	19980826	Product specification	-	-		

14. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

 Please consult the most recently issued document before initiating or completing a design.

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